

HA12237F

Audio Signal Processor for Cassette Deck

REJ03F0137-0100
 (Previous: ADE-207-343)
 Rev.1.00
 Jun 15, 2005

Description

HA12237F is silicon monolithic bipolar IC providing PB equalizer, REC equalizer system, ALC and each electronic control switch in one chip.

Functions

- PB equalizer × 2 channel
- REC equalizer × 2 channel
- ALC (Automatic Level Control)
- REC mute
- REC head return switch
- Line Amp. × 2 channel
- Line mute

Features

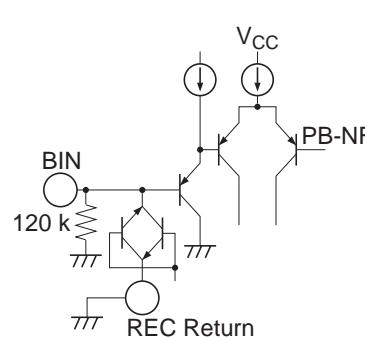
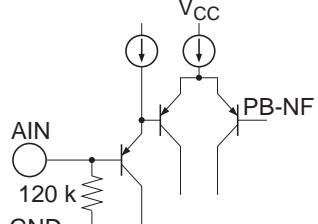
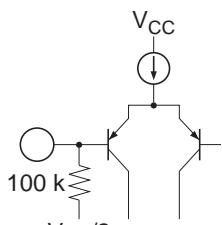
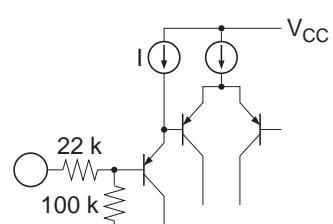
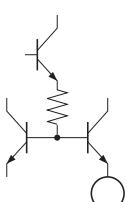
- REC equalizer is very small number of external parts built-in 2 types of frequency characteristics.
- TYPE I REC correspondence, High-speed dubbing correspondence.
- PB equalizer circuit built-in 2 types of frequency characteristics. (external parts of capacitor only)
- Head control switch built-in.
- Line mute switch built-in.
- Controllable from direct micro-computer output.

Parallel Data Format

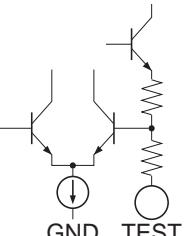
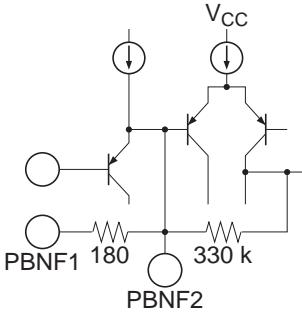
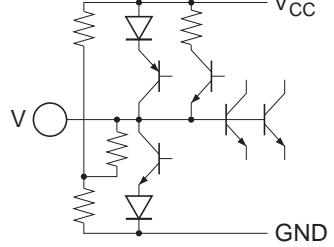
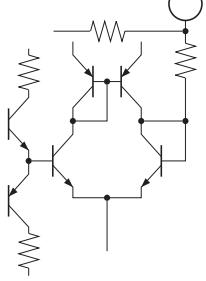
Pin No.	Pin Name	Lo	Hi
11	ALC ON/OFF	ALC OFF	ALC ON
12	High/Norm	Normal speed	High speed
13	A/B	B	A
	REC Return ON/OFF	Return OFF	Return ON
14	MUTE ON/OFF	MUTE OFF	MUTE ON
15	REC MUTE OFF/ON	REC MUTE ON	REC MUTE OFF

Pin Description, Equivalent Circuit

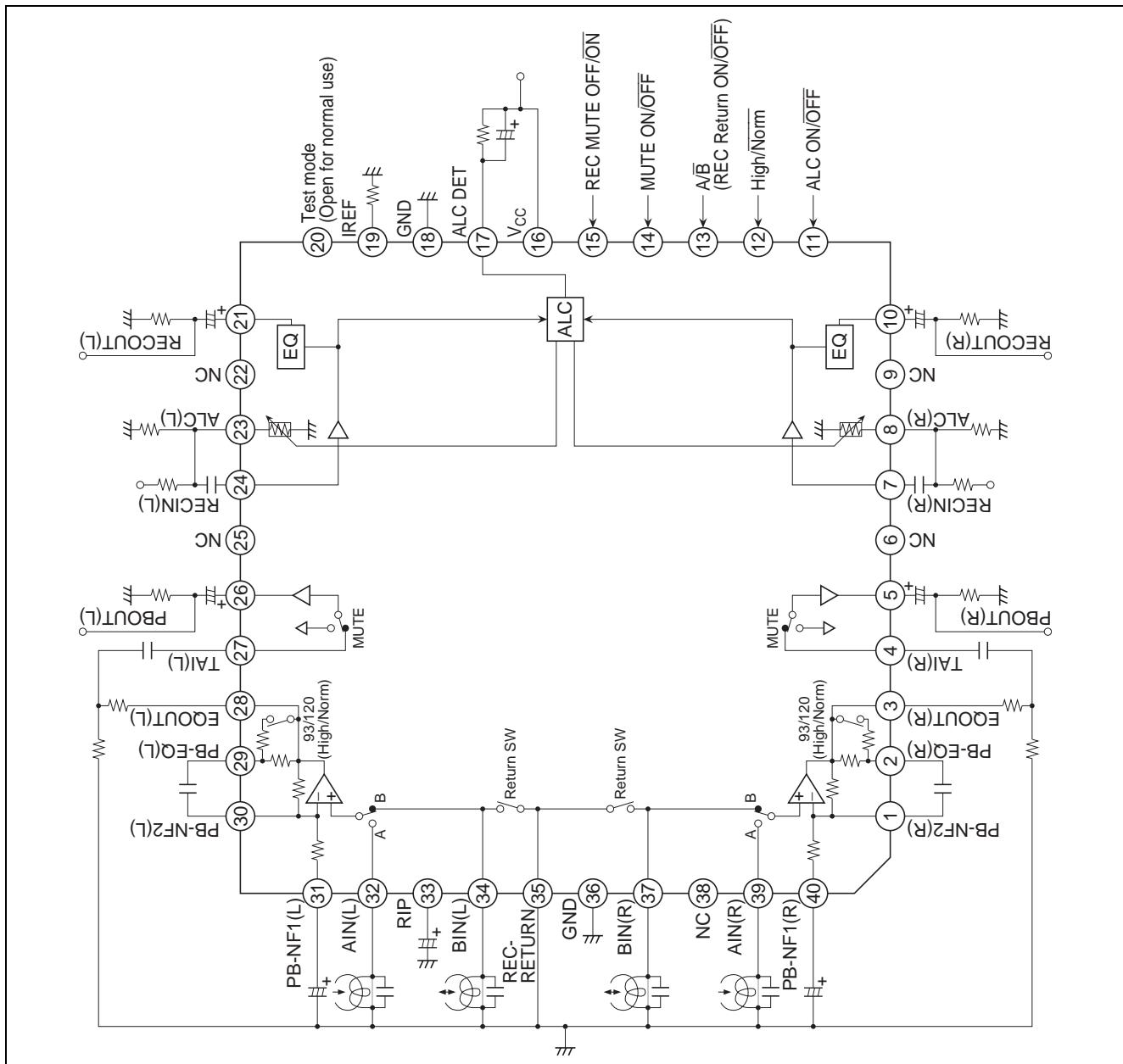
($V_{CC} = 12 \text{ V}$, $T_a = 25^\circ\text{C}$, No Signal, The value in the table shows typical value.)

Pin No.	Pin Name	Note	Equivalent Circuit	Description
16	V_{CC}	$V = V_{CC}$		V_{CC} pin
21	RECOUT(L)	$V = V_{CC}/2$		REC output
10	RECOUT(R)			
26	PBOUT(L)			PB output
5	PBOUT(R)			
28	EQOUT(L)	$V = 2.9 \text{ V}$		EQ output
3	EQOUT(R)			
35	REC-RETURN	$V = 0 \text{ V}$		REC Return
34	BIN(L)			PB B deck input
37	BIN(R)			
32	AIN(L)	$V = 0 \text{ V}$		PB A deck input
39	AIN(R)			
24	RECIN(L)	$V = V_{CC}/2$		REC-EQ input
7	RECIN(R)			
27	TAI(L)	$V = V_{CC}/2$		Tape input
4	TAI(R)			
11	ALC ON/OFF	(Control voltage = 3 V)		Mode control input
12	High/Norm			
13	A/B			
14	MUTE ON/OFF			
15	REC MUTE OFF/ON			
19	IREF	$V = 1.2 \text{ V}$		Equalizer reference current input

Pin Description, Equivalent Circuit (cont.)(V_{CC} = 12 V, Ta = 25°C, No Signal, The value in the table shows typical value.)

Pin No.	Pin Name	Note	Equivalent Circuit	Description
18, 36	GND			GND pin
6, 9, 22, 25, 38	NC			NC pin
20	Test mode		 GND TEST	Test mode pin
31	PB-NF1(L)	V = 0.6 V	 PBNF1 180 330 k PBNF2	PB EQ feed back
40	PB-NF1(R)			
30	PB-NF2(L)			
1	PB-NF2(R)			
33	RIP	V = V _{CC} /2	 VCC GND	Ripple filter
29	PB-EQ(L)			NAB output
2	PB-EQ(R)			

Block Diagram



Functional Description

Power Supply Range

This IC designed to operate on single supply, shown by table 1.

Table 1 Supply Voltage

Item	Power Supply Range
Single supply	6.5 V to 15.0 V

Reference Voltage

This device provide the reference voltage of half the supply voltage that is the signal grounds. As the peculiarity of this device, the capacitor for the ripple filter is very small about 1/100 compared with their usual value. The block diagram is shown as figure 1.

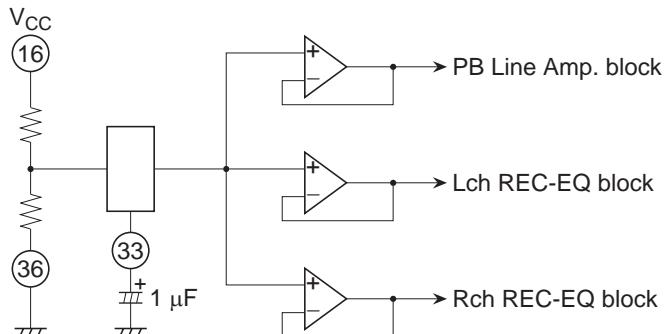


Figure 1 Block Diagram of Reference Supply Voltage

Operating Mode Control

HA12235F provide fully electronic switching circuits. And each operating mode control is controlled by parallel data (DC voltage).

Table 2 Threshold Voltage (V_{TH})

Pin No.	Lo	Mid	Hi	Unit	Test Condition
11 to 15	-0.2 to 0.5	—	2.4 to V _{cc}	V	Input Pin Measure

Notes: 1. Each pins are on pulled down with 100 kΩ internal resistor. Therefore, it will be low-level when each pins are open.
 2. Over shoot level and under shoot level of input signal must be the standardized.
 (High: V_{CC}, Low: -0.2 V)

Test Mode

Test mode becomes when pin 20 is shorted to GND. Please open pin 20 on the occasion of mount.

Block Diagram

As this IC is built-in REC return switch, the configuration system can be simple system using a few external component and the REC/PB head.

About these logics, please look at the Parallel Data Format.

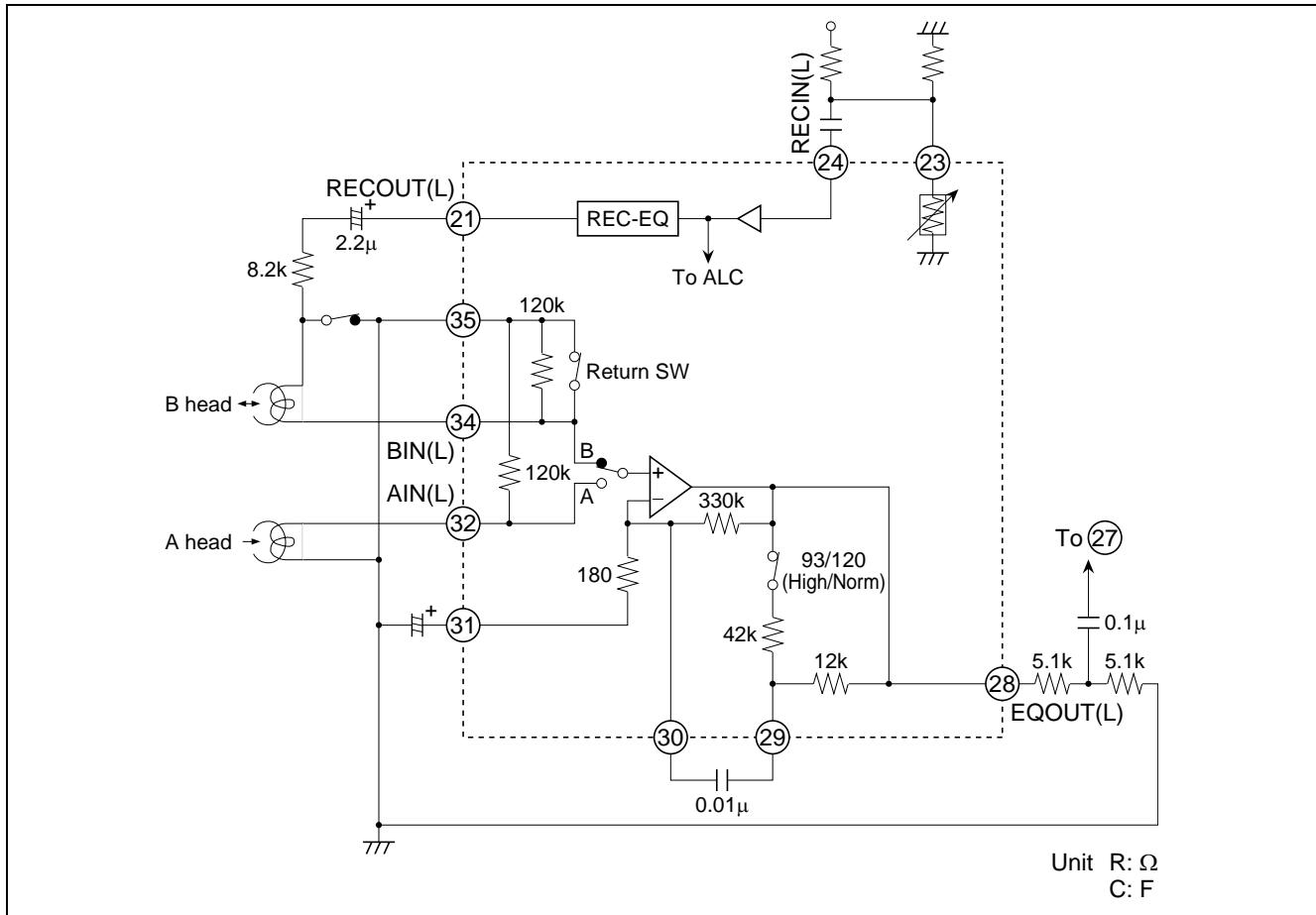


Figure 2 Block Diagram (Lch)

PB Equalizer

The gain establishment of PB-EQ considers PB output level {(internal Line Amp. + PB Amp.) = 580 mVrms} like figure 3 at the target.

After replace RA and RB with a half-fix volume, adjust level.

REC-EQ adjust the gain in front of input to this IC.

The level diagram of 1 kHz is shown figure 3.

Please set “RA + RB ≥ 10 kΩ”

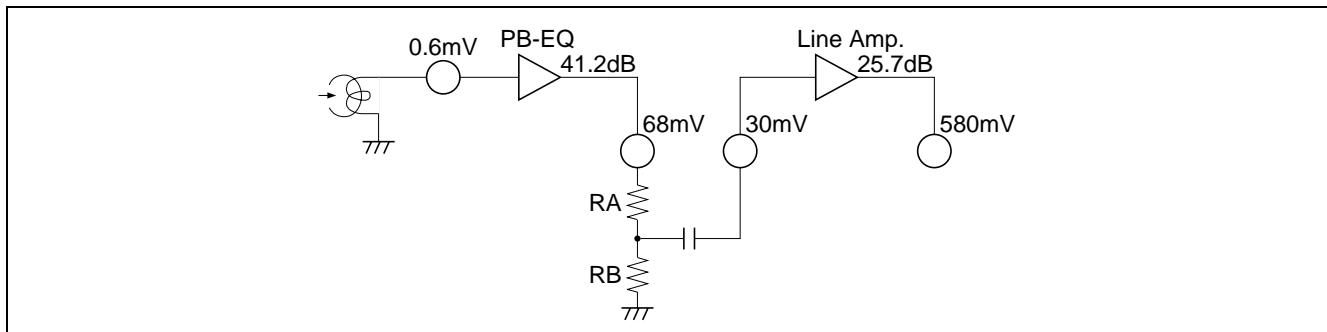


Figure 3 PB System Level Diagram (1 kHz)

Line Mute

This IC is built-in with mute circuit to Line Amp.

A mute control does with Low/High of pin 14.

Reducing pop noise is so much better 10 k Ω to 22 k Ω resistor to pin 14 in series and 1 μ F to 22 μ F capacitor.

A mute is not built-in when doing a power ON/OFF.

Please correspond to it, on the side of a set system.

REC Equalizer

REC-EQ gain adjust before the input of this IC.

R_L needs the value more than 5.6 k Ω based on the output at reference input.

Because mode establishment resistances are built-in, REC-EQ frequency characteristics are respectively fixed value.

In case the change of the frequency characteristics are necessary, please inquire the responsible agent because the adjustment of resistors is necessary.

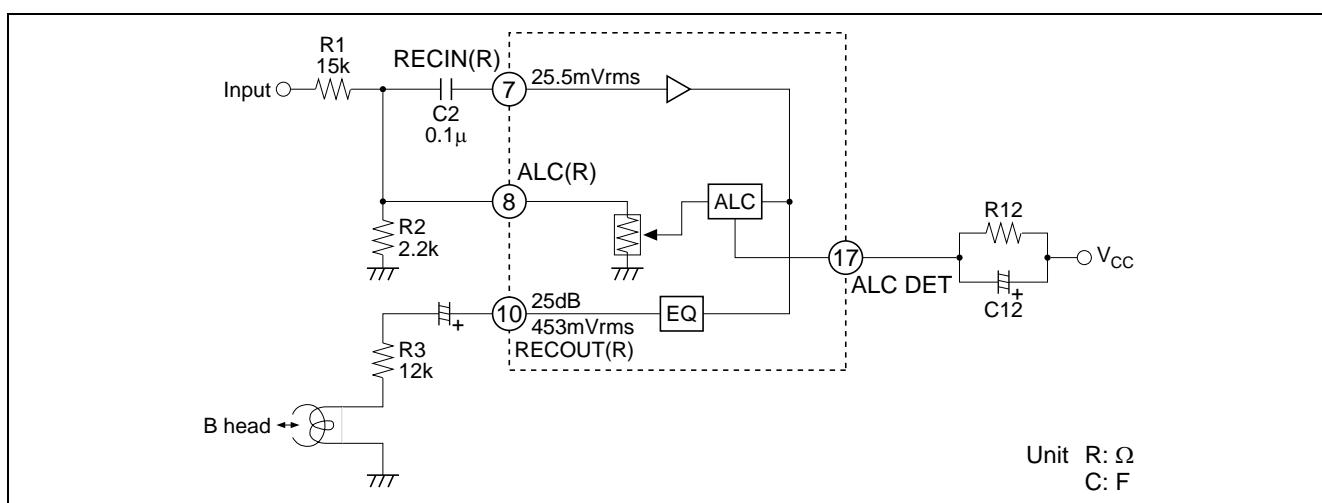


Figure 4 REC-EQ Block Diagram

ALC (Automatic Level Control)

ALC is the input decay rate variable system. It has internal variable resistors of pin 8 (pin 23) by REC signal that is inputted to pin 7 (pin 24).

Pin 17 is detector pin.

The signal input pin is pin 7 (pin 24). Resistor R1, R2 and capacitor C2, external components, for the input circuit are recommended as figure 4. There are requested to use value of the block diagram figure for performance maintenance of S/N, T.H.D. etc.

Figure 5 shows the relation with R1 and C1 front input point and RECOUP.

ALC operation level acts for the center of +4.5 dB to standard level (453 mVrms).

Then, adopted maximum value circuit, ALC is operated by a large channel of signal.

ALC ON/OFF can switch it by pin 11. Please do ALC ON, after it does for one time ALC OFF inevitably, for ALC time to start usefully, in order to reset ALC circuit.

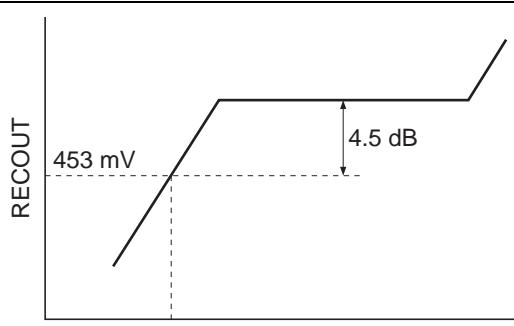


Figure 5 ALC Operation Level

Absolute Maximum Ratings

(Ta = 25°C)

Item	Symbol	Rating	Unit	Note
Maximum supply voltage	V _{CC} Max	16	V	
Power dissipation	P _T	625	mW	T _a ≤ 75°C
Operating temperature	T _{opr}	-40 to +75	°C	
Storage temperature	T _{stg}	-55 to +125	°C	
Operating voltage	V _{opr}	6.5 to 15	V	

Note: HA12235F operates on single supply voltage.

Electrical Characteristics

Item	Symbol	Test Condition						Application Terminal					
		A/B	High/ Norm	ALC ON/OFF	f _{in} (Hz)	V _{in} (mV/rms)	Other	Min	Typ	Max	R	L	
Quiescent current	I _Q	A	Norm	OFF	—	—	No signal	—	12.2	20.2	mA	—	—
Logical threshold	V _{IL}	—	—	—	—	—	—	-0.2	—	0.5	V	—	—
V _{IH}	—	—	—	—	—	—	—	2.4	—	V _{CC}	V	—	—
PB-REC crosstalk	GT PB/REC(1)	A	Norm	OFF	1k	*1	REC-EQ → PB-EQ	50.0	60.0	—	dB	7	24
	GT PB/REC(2)	A	Norm	OFF	1k	6.0	PB-EQ → REC-EQ	60.0	70.0	—	dB	39	32
PB-EQ gain	GV PB(1)	A/B	Norm	OFF	1k	0.6	—	37.4	40.4	43.4	dB	39/37	28/29
	GV PB(2)	A	Norm	OFF	10k	0.6	—	33.3	36.3	39.3	dB	39	32
	GV PB(3)	A	High	OFF	20k	0.6	—	31.2	34.2	37.2	dB	39	32
PB-EQ maximum output level	V _{omax} PB	A	Norm	OFF	1k	—	THD = 1%	0.3	0.6	—	Vrms	39	32
PB-EQ T.H.D.	THD PB	A/B	Norm	OFF	1k	2.4	—	0.2	0.5	%	39/37	28/29	3
PB-EQ noise voltage	VN PB	A/B	Norm	OFF	—	—	R _g = 680Ω, DIN-AUDIO	—	110	200	µVrms	39/37	28/29
PB-EQ channel separation	CT R/L(1)	A	Norm	OFF	1k	6.0	—	50.0	60.0	—	dB	39	32
PB-EQ crosstalk	CT A/B	A/B	Norm	OFF	1k	6.0	—	60.0	70.0	—	dB	39/37	28/29
Line Amp. gain	G _v LA	A	Norm	OFF	1k	30.0	—	24.2	25.7	27.2	dB	4	27
Line Amp. T.H.D.	THD LA	A	Norm	OFF	1k	30.0	—	0.05	0.30	%	4	27	5
Line Amp. maximum output level	V _{omax} LA	A	Norm	OFF	1k	—	THD = 1%	1.16	1.40	—	Vrms	4	27
Line mute attenuation	L-MUTE ATT	A	Norm	OFF	1k	120.0	—	70.0	80.0	—	dB	4	27

Notes: 1. Large level without clipping
 2. V_{CC} = 6.5V

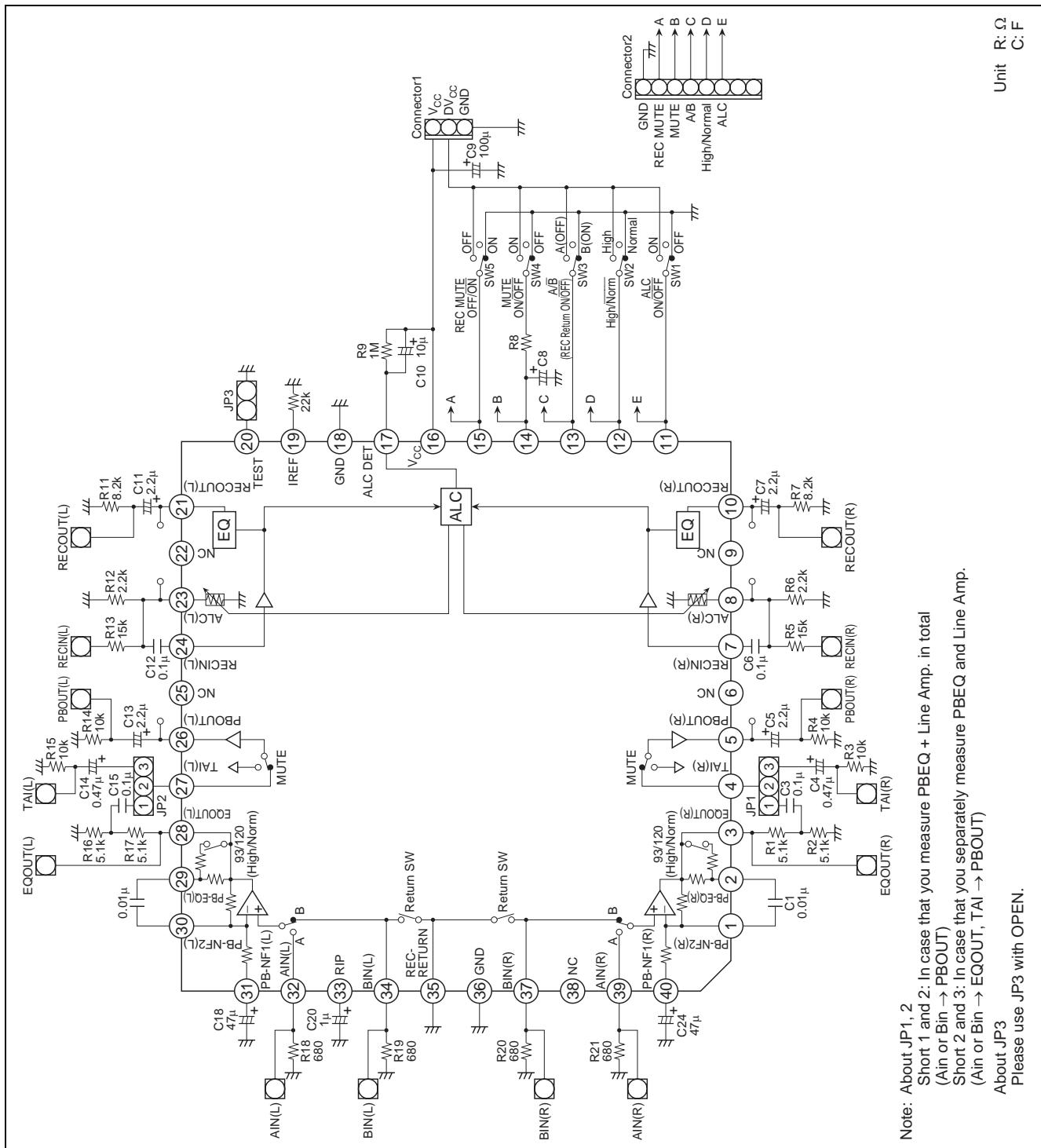
Electrical Characteristics (cont.)

Item	Symbol	IC Condition	Test Condition						Application Terminal						
			A/ \bar{B}	High/Norm	ALC On/Off	V _{in} (Hz)	V _{in} (mVrms)	Other	Min	Typ	Max	Unit	R	L	COM/Remark
ALC operate level	ALC	ON	A	Norm	ON	1k	+12		2.0	4.5	7.0	dB	7	24	10 21
REC-EQ frequency characteristics	GV REC-NN1	OFF	A	Norm	OFF	1k	-26		23.5	25.0	26.5	dB	7	24	10 21
Normal speed	GV REC-NN2	OFF	A	Norm	OFF	5k	-26		26.9	28.9	30.9	dB	7	24	10 21
REC-EQ frequency characteristics	GV REC-NN3	OFF	A	Norm	OFF	10k	-26		33.2	35.7	38.2	dB	7	24	10 21
High speed	GV REC-HN1	OFF	A	High	OFF	2k	-26		23.4	24.9	26.4	dB	7	24	10 21
REC-EQ channel separation	GV REC-HN2	OFF	A	High	OFF	10k	-26		26.5	28.5	30.5	dB	7	24	10 21
REC-MUTE attenuation	GV REC-HN3	OFF	A	High	OFF	20k	-26		33.4	35.9	38.4	dB	7	24	10 21
REC-MUTE ATT	CT R/L(2)	OFF	A	Norm	OFF	1k	*1		61.0	70.0	—	dB	7	24	10 21
REC-EQ maximum output level	R-MUTE ATT	OFF	A	Norm	OFF	1k	*1		66.0	76.0	—	dB	7	24	10 21
REC-EQ T.H.D.	Vmax REC	OFF	A	Norm	OFF	1k	—	THD = 1%	0.7	1.0	—	Vrms	7	24	10 21
REC-EQ S/N	THD REC	OFF	A	Norm	OFF	1k	0		—	0.2	0.5	%	7	24	10 21
	S/N REC	OFF	A	Norm	OFF	1k	—	Rg = 2.2kΩ, A-WTG	55.0	59.0	—	dB	—	—	10 21

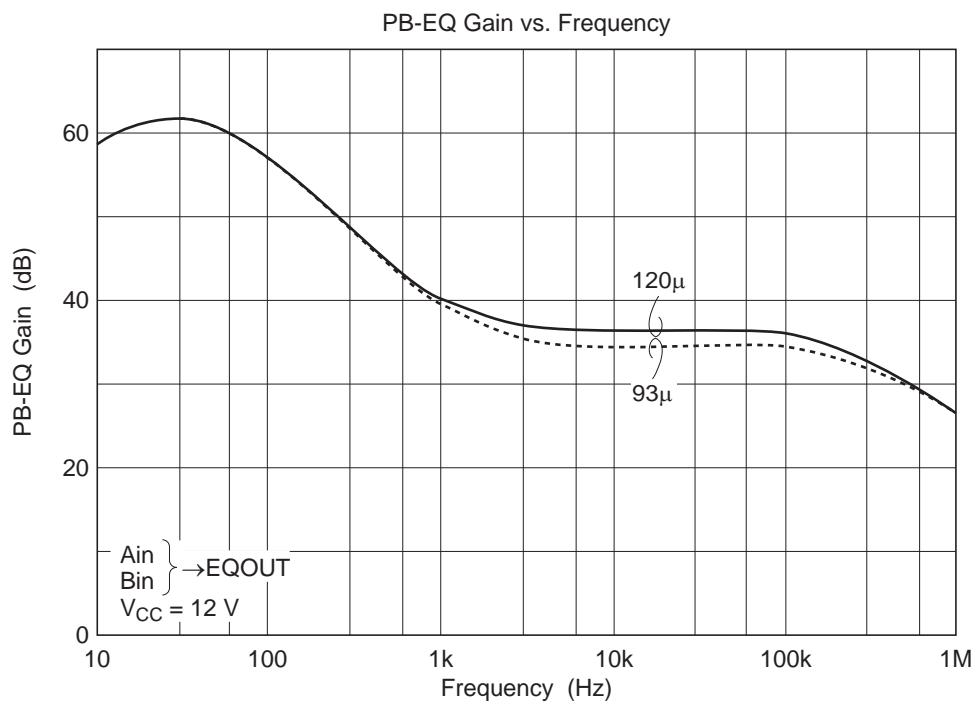
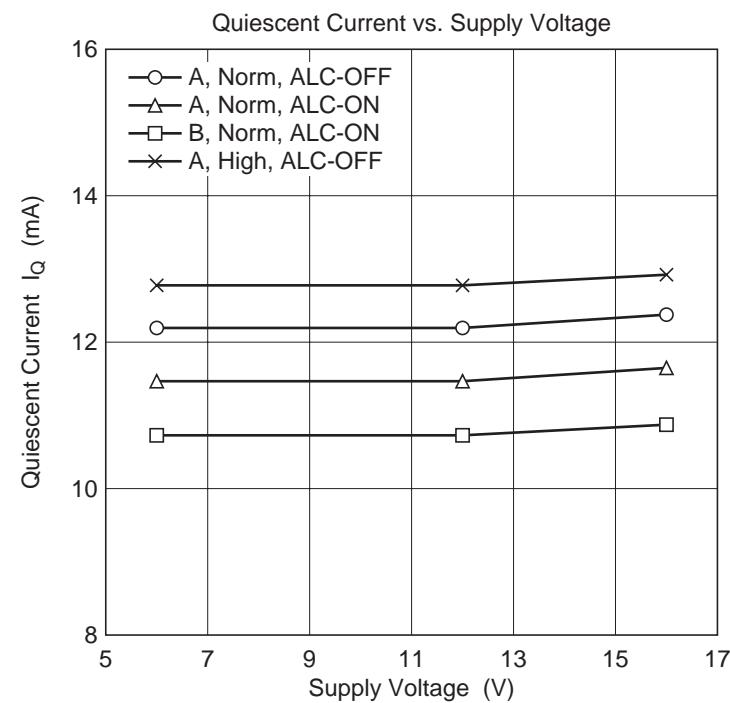
Notes: 1. Large level without clipping

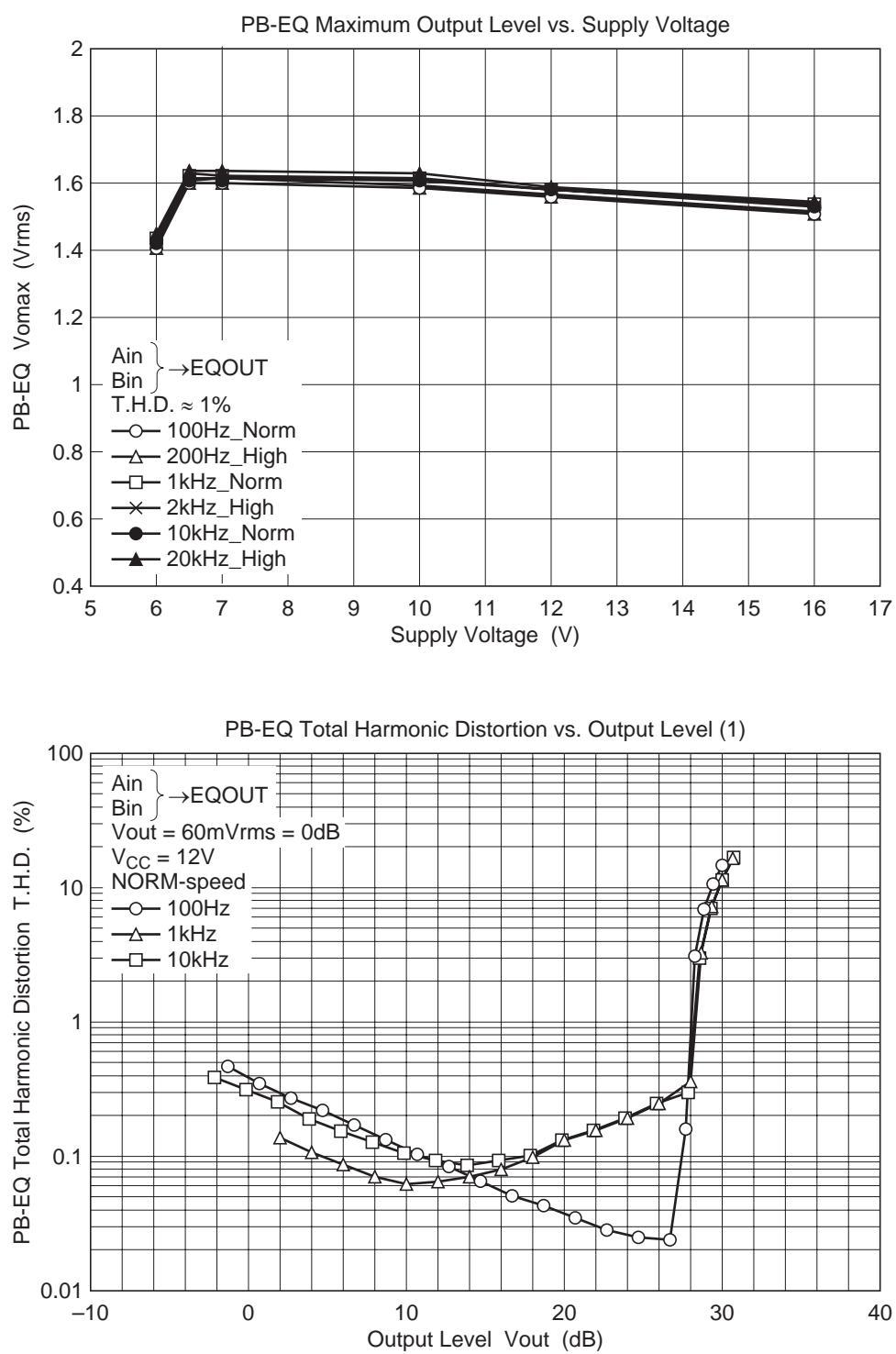
2. V_{CC} = 6.5V

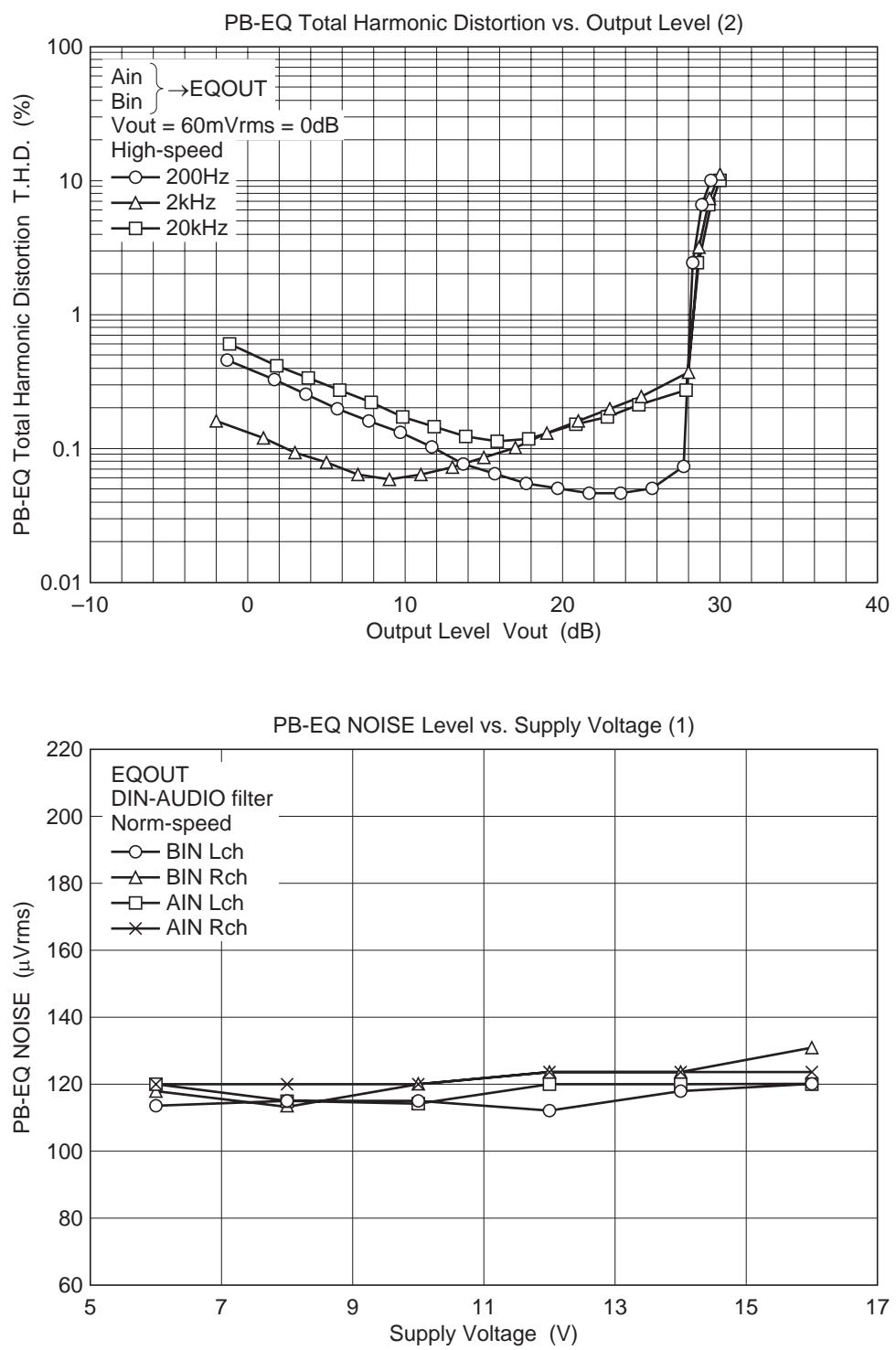
Test Circuit

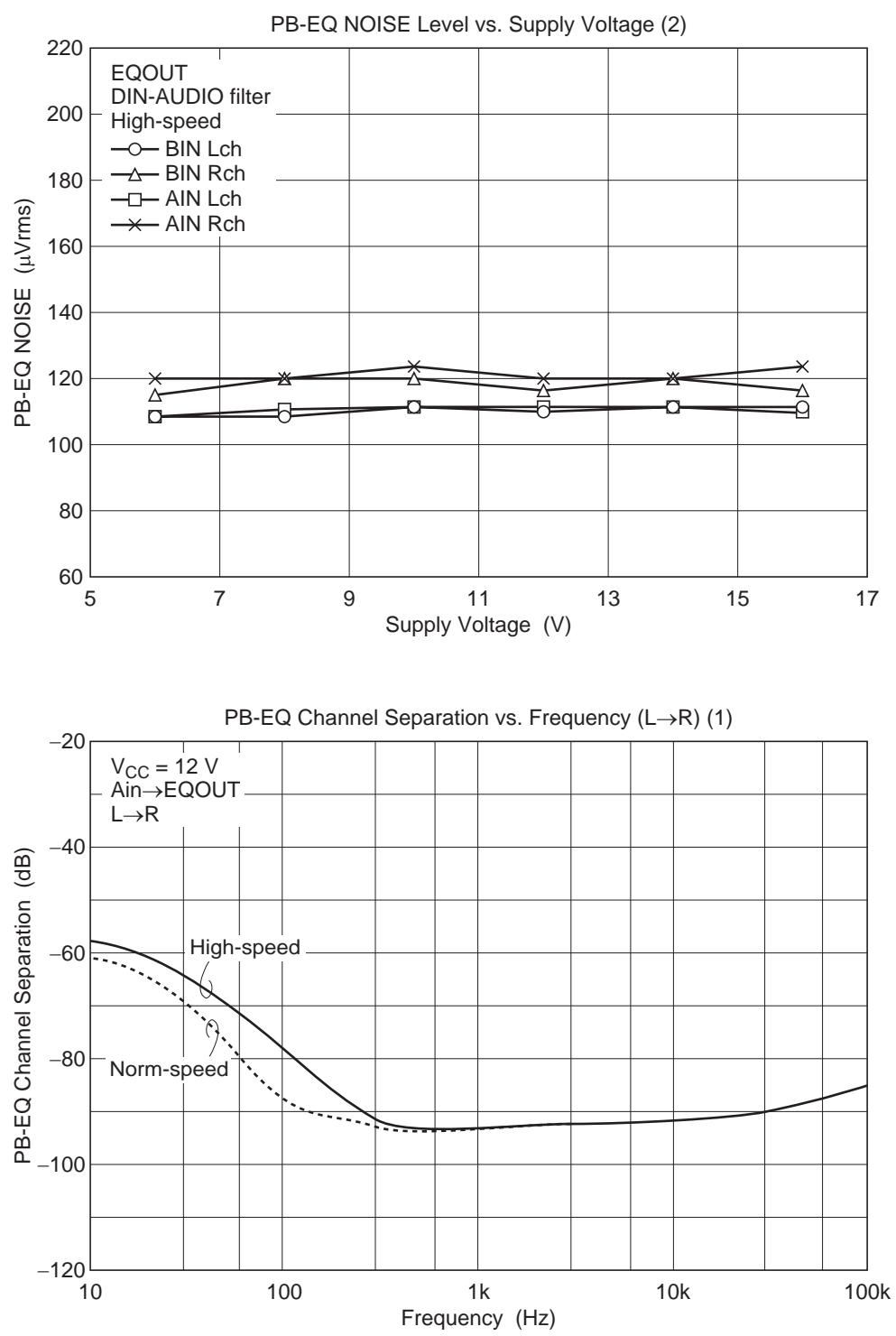


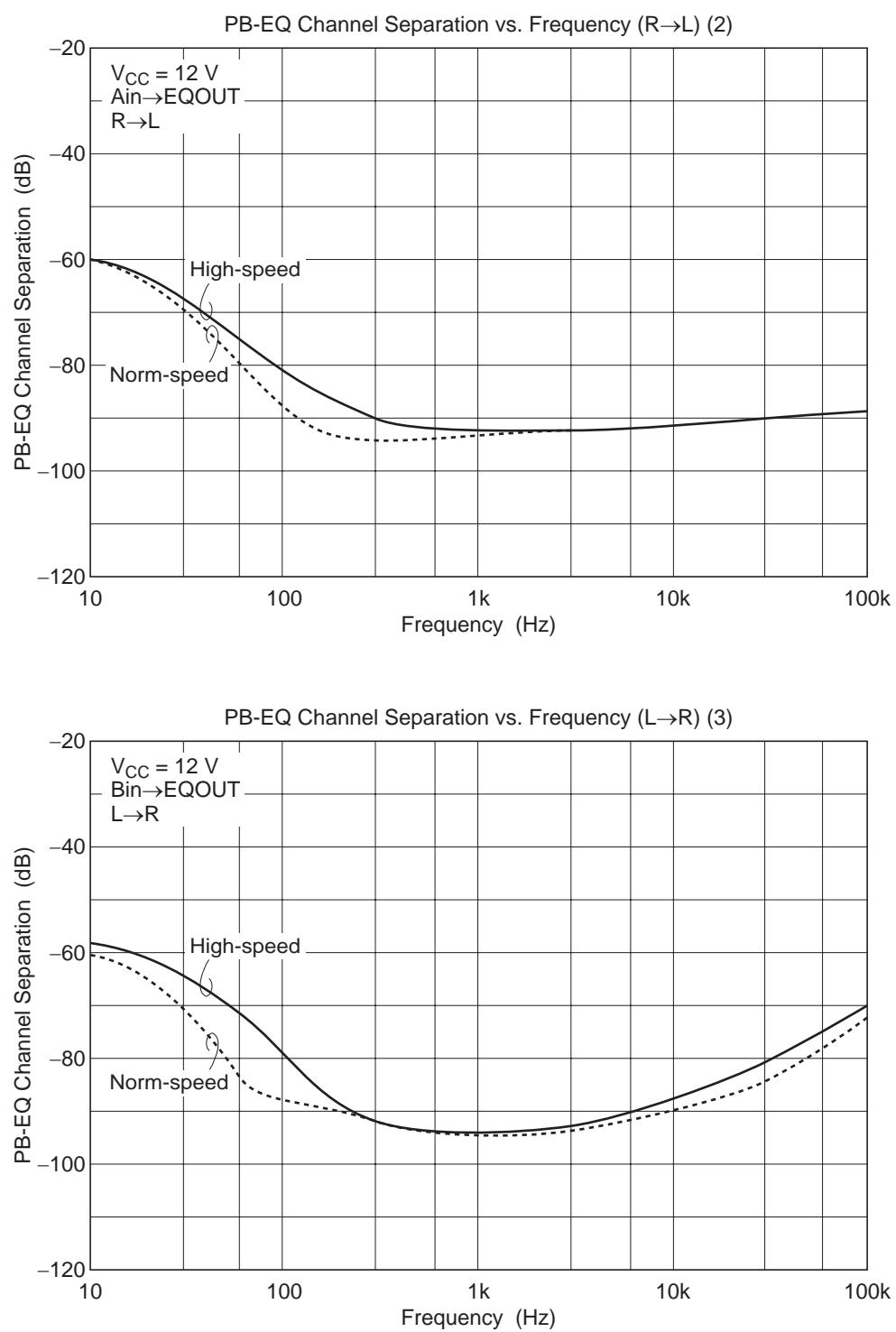
Characteristic Curves

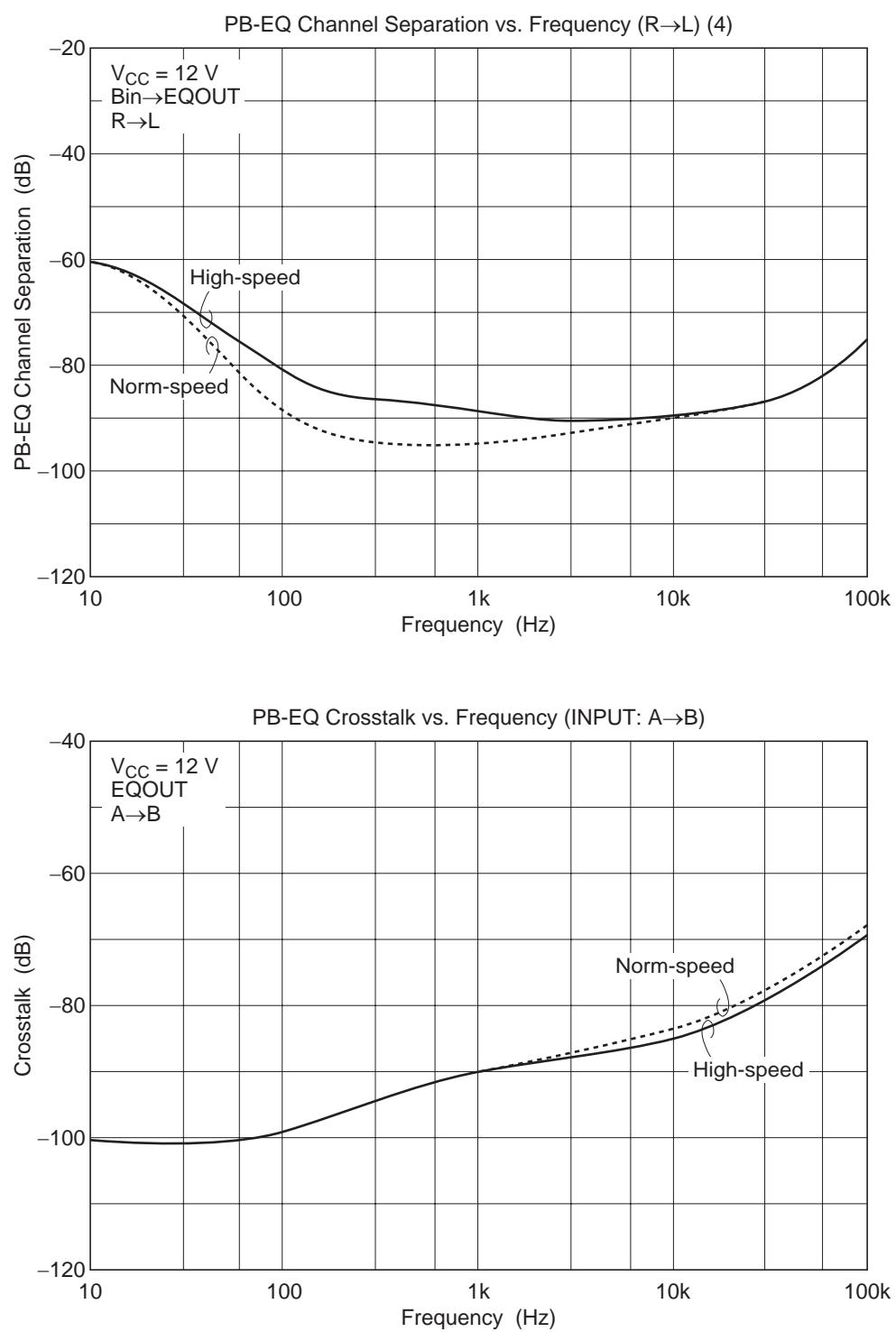


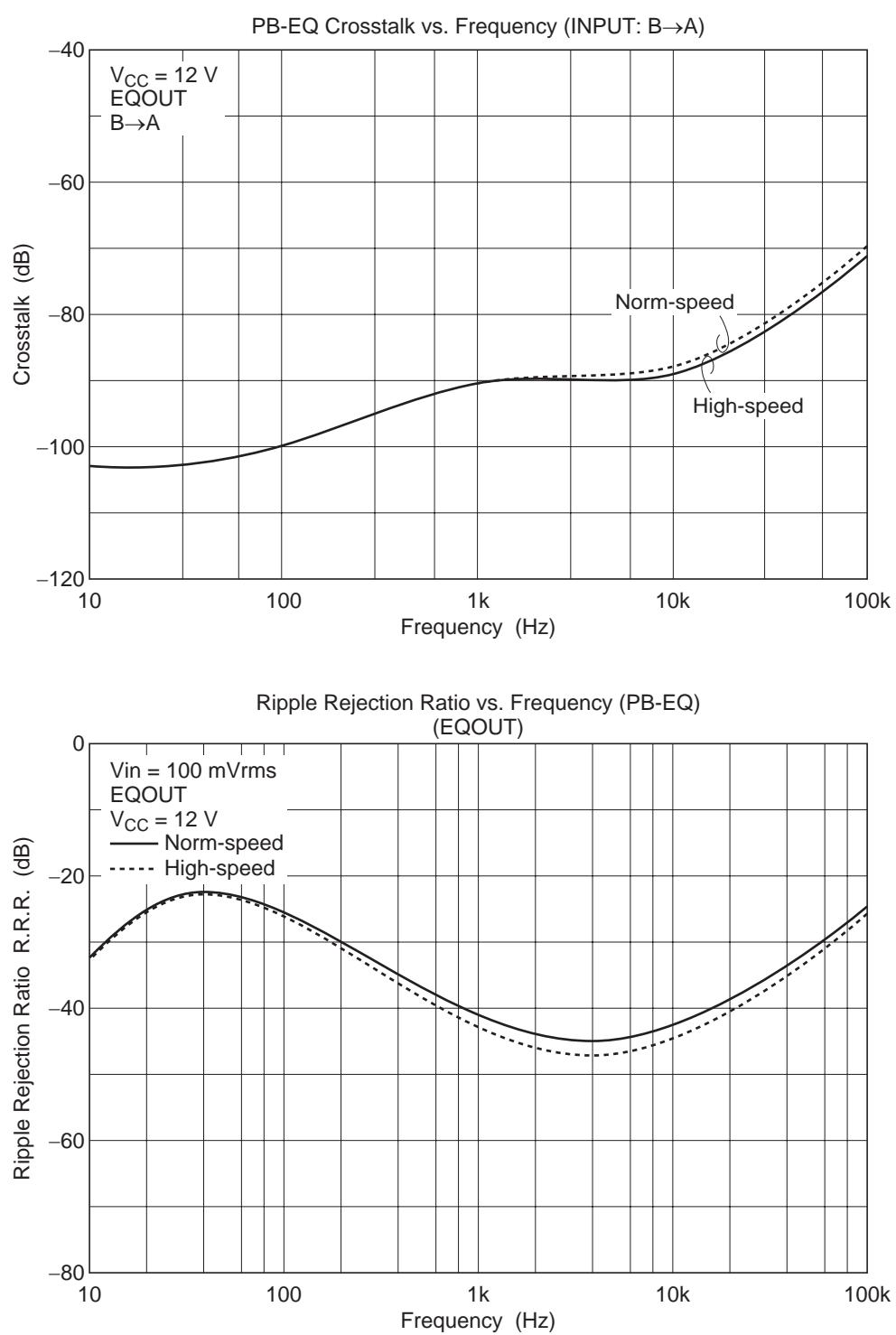


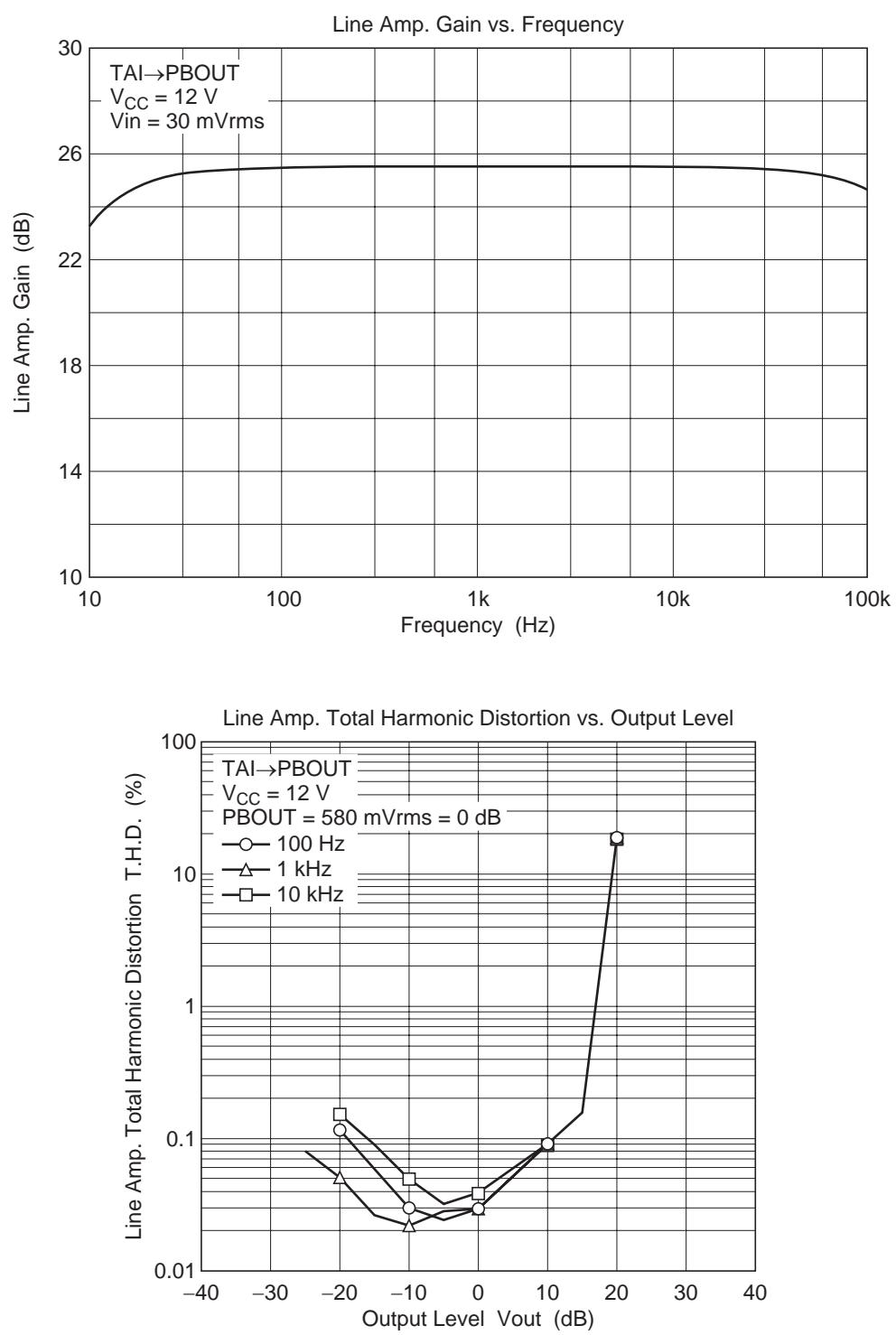


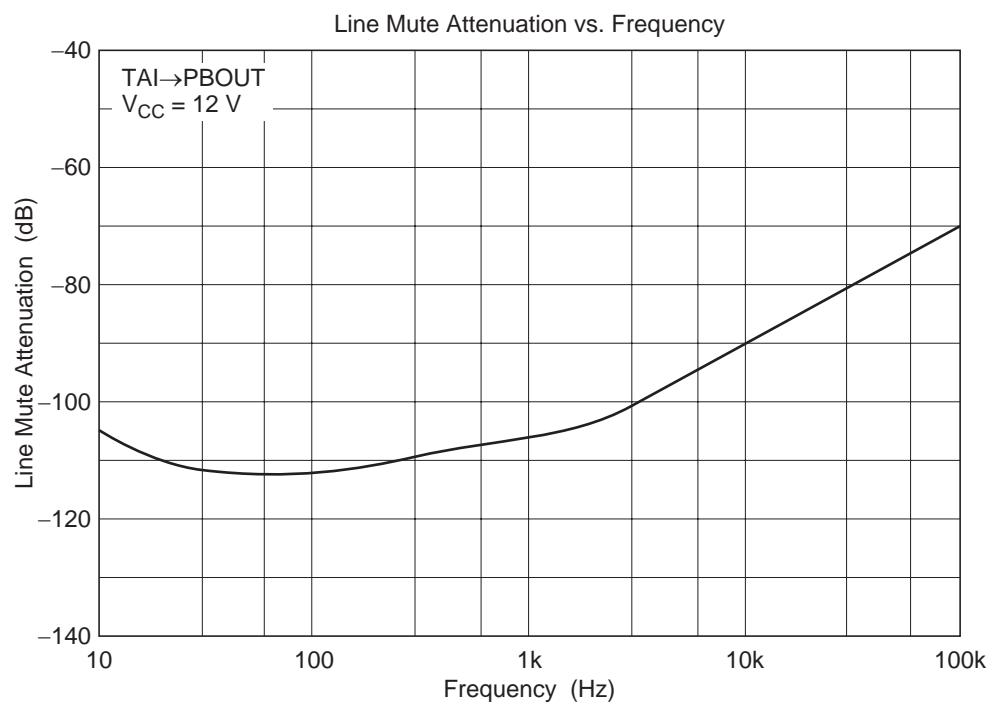
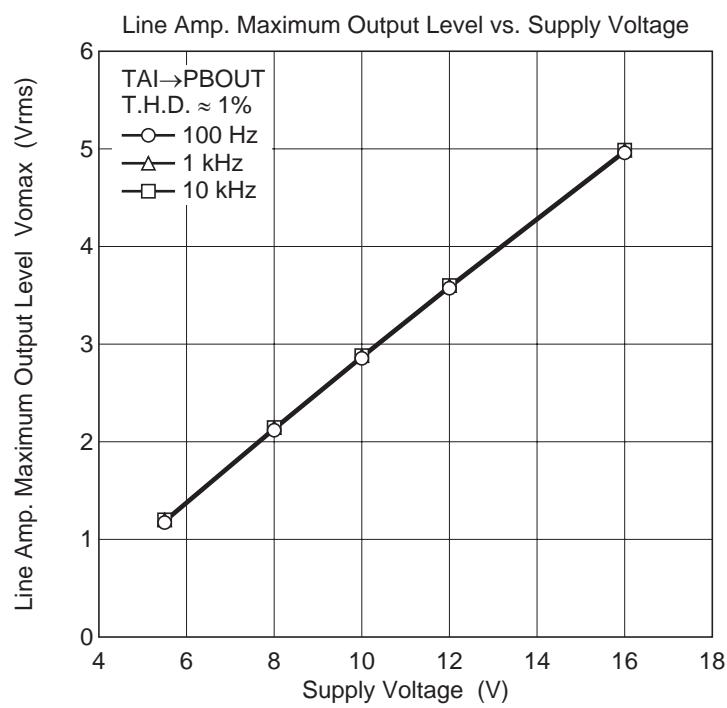


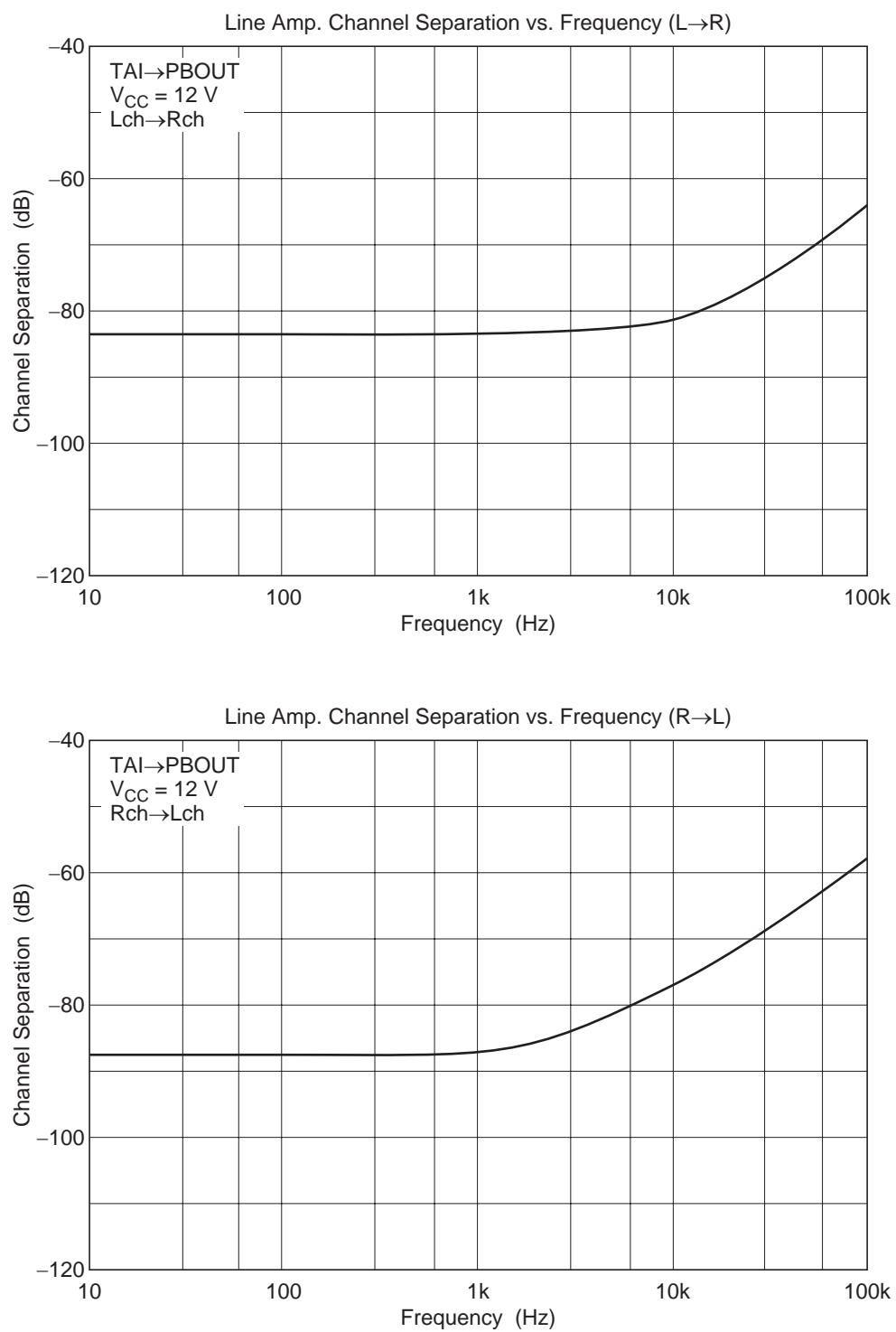


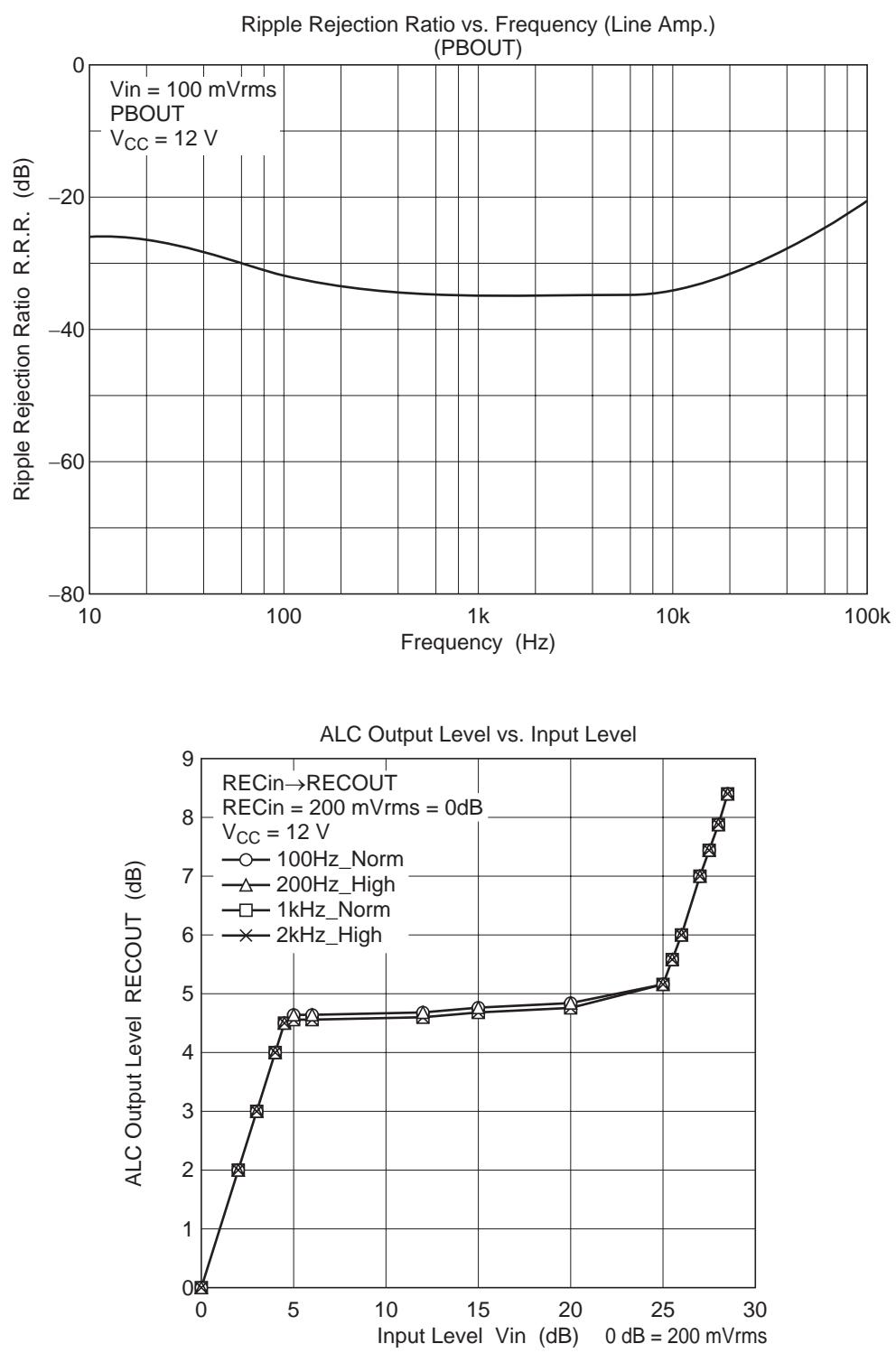


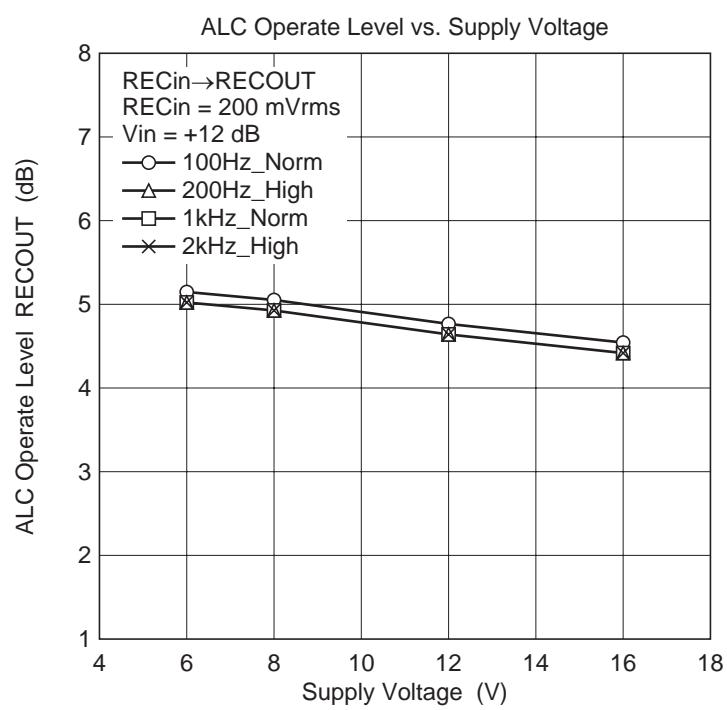
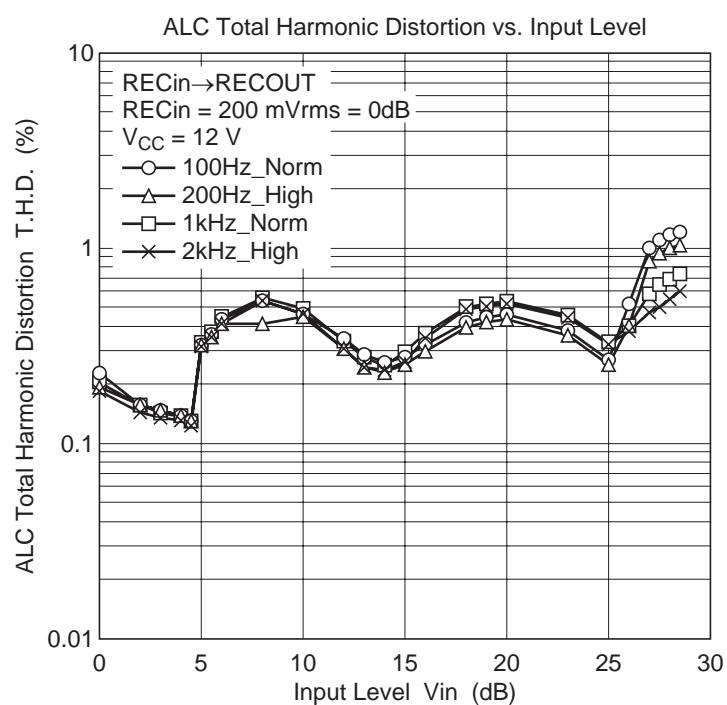


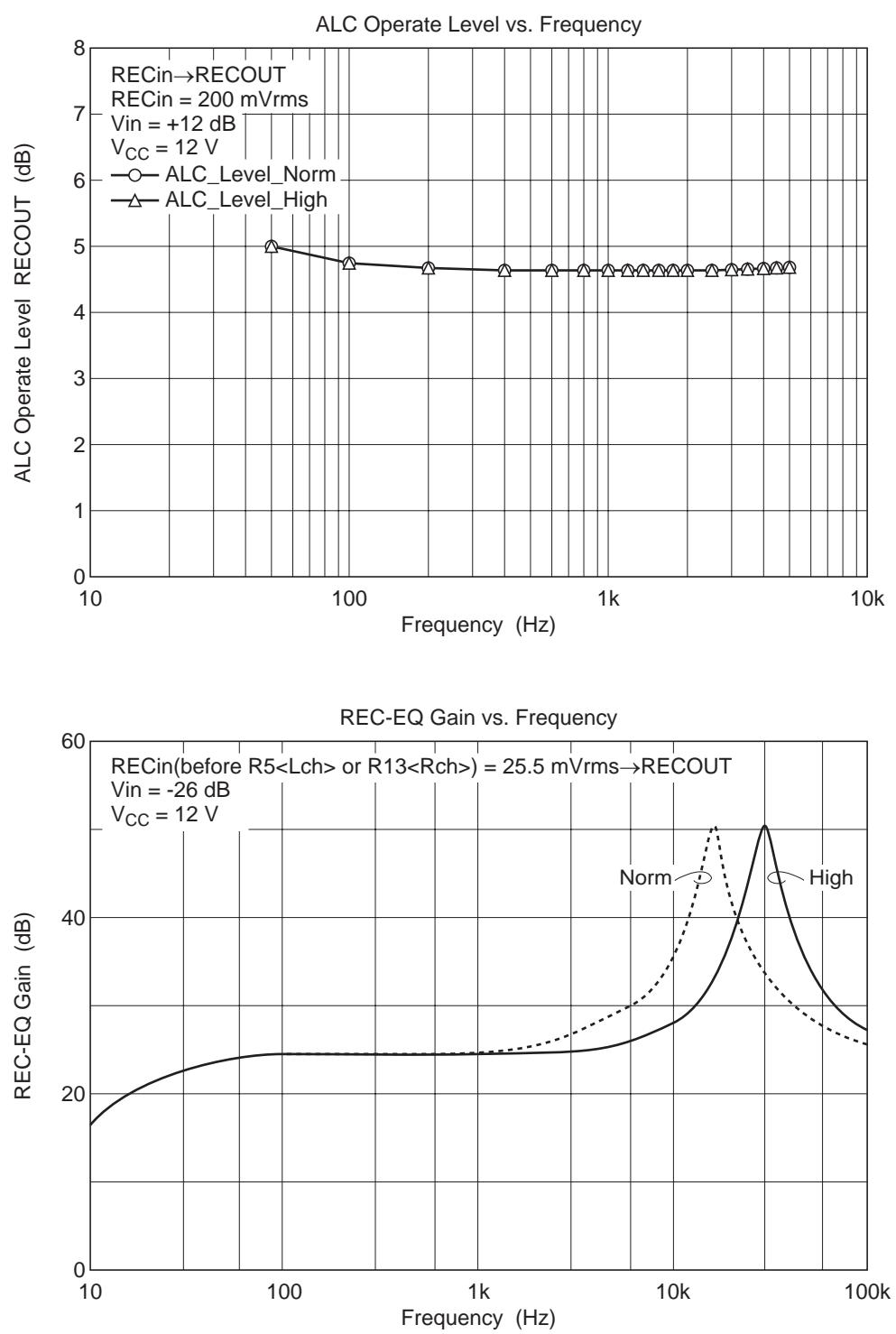


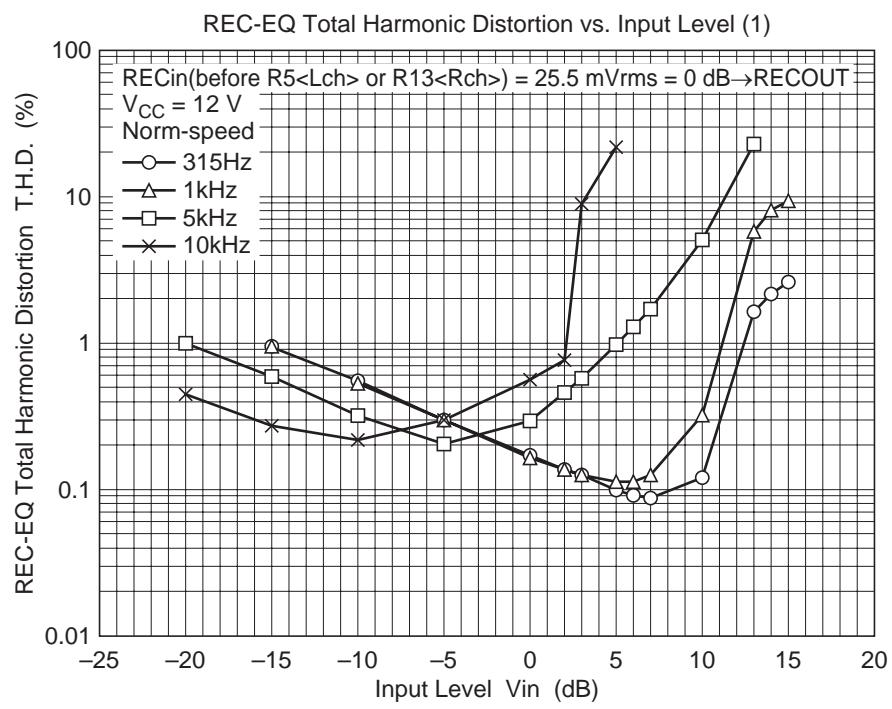
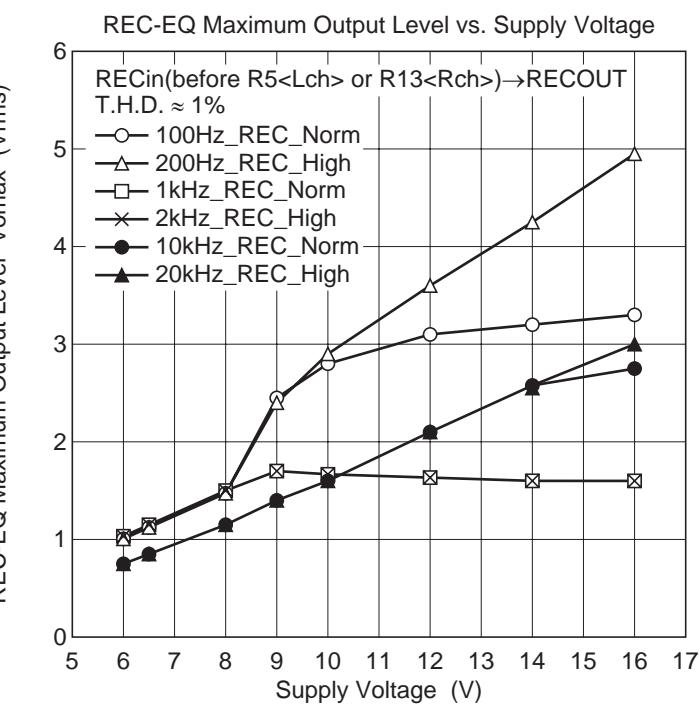


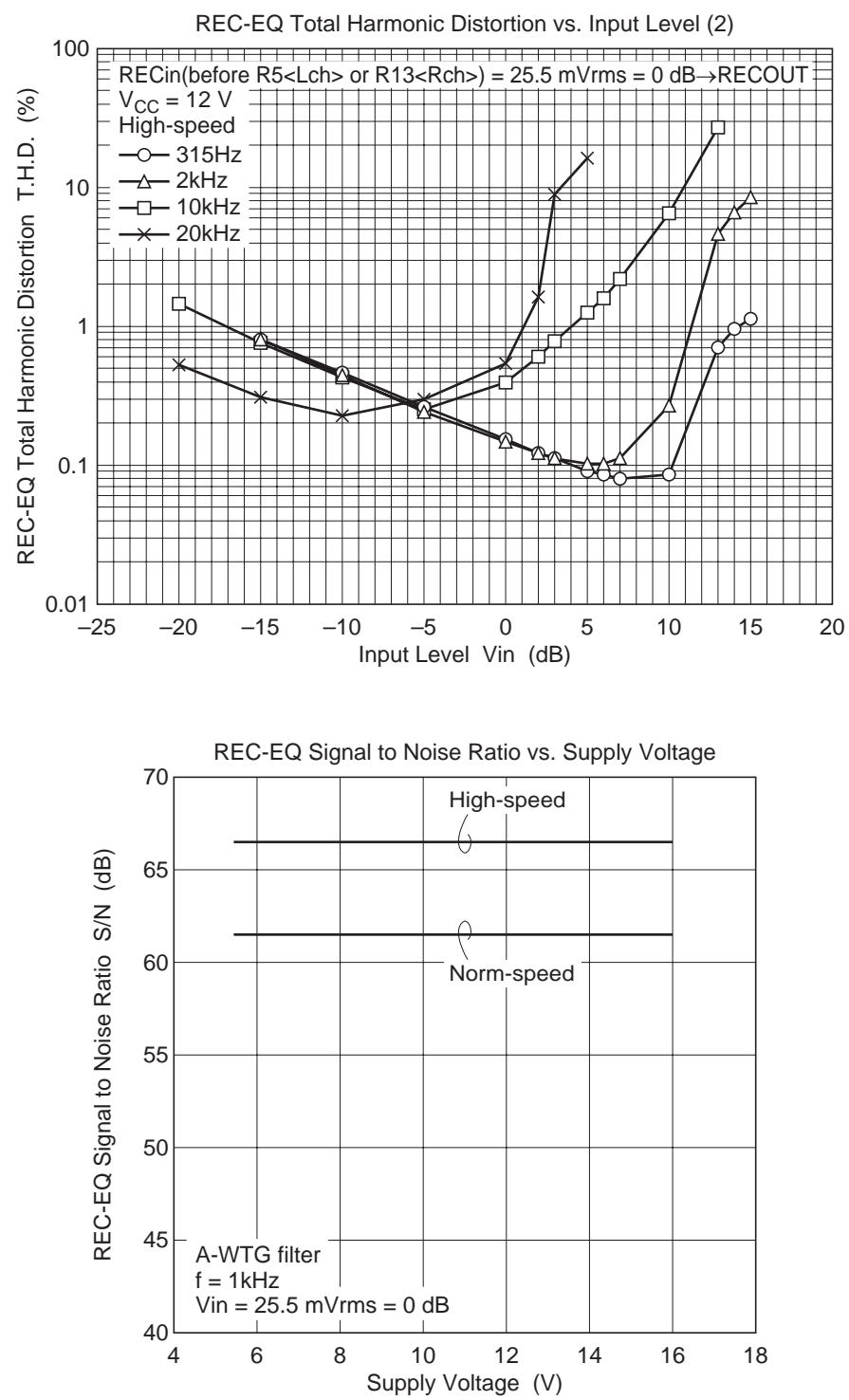


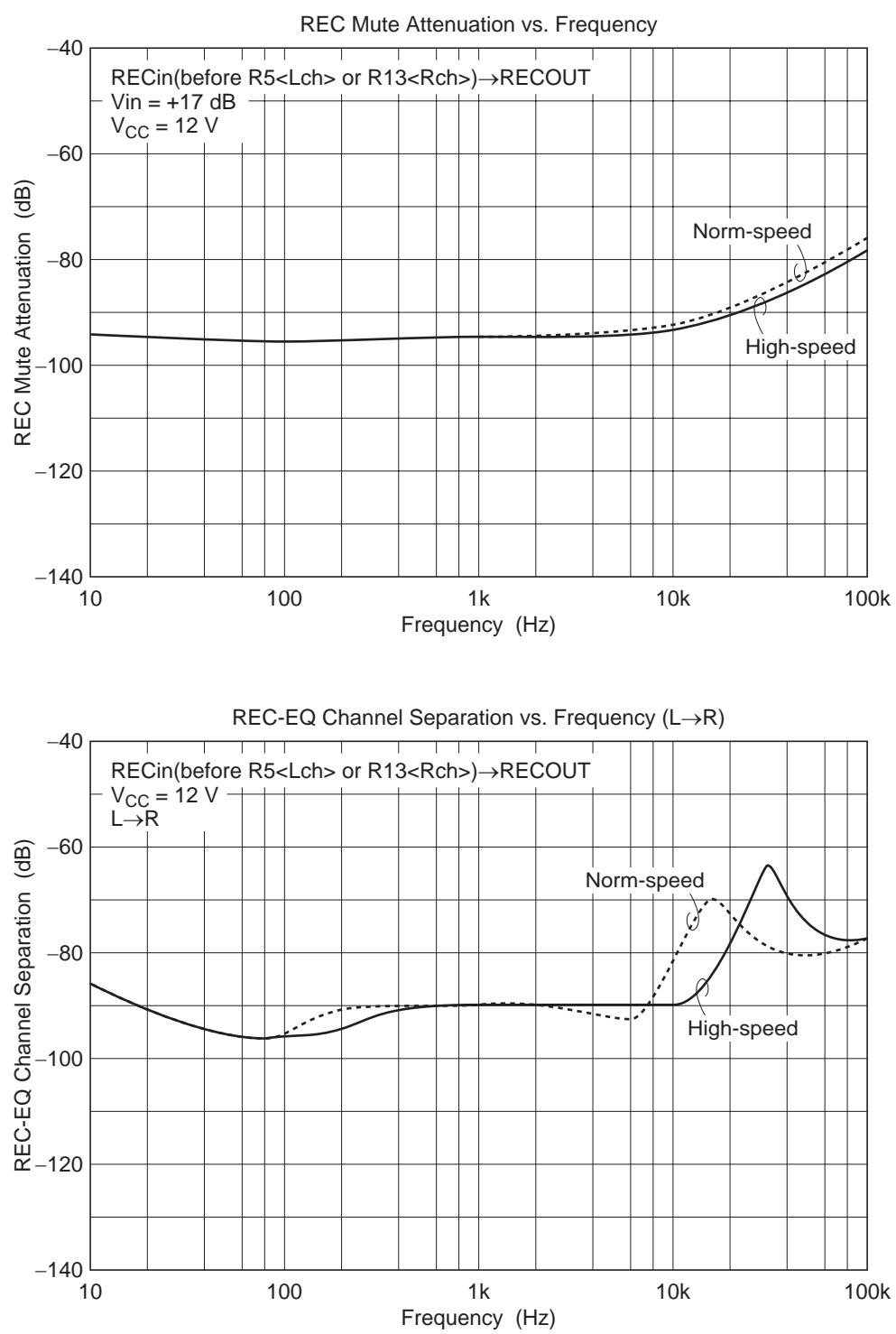


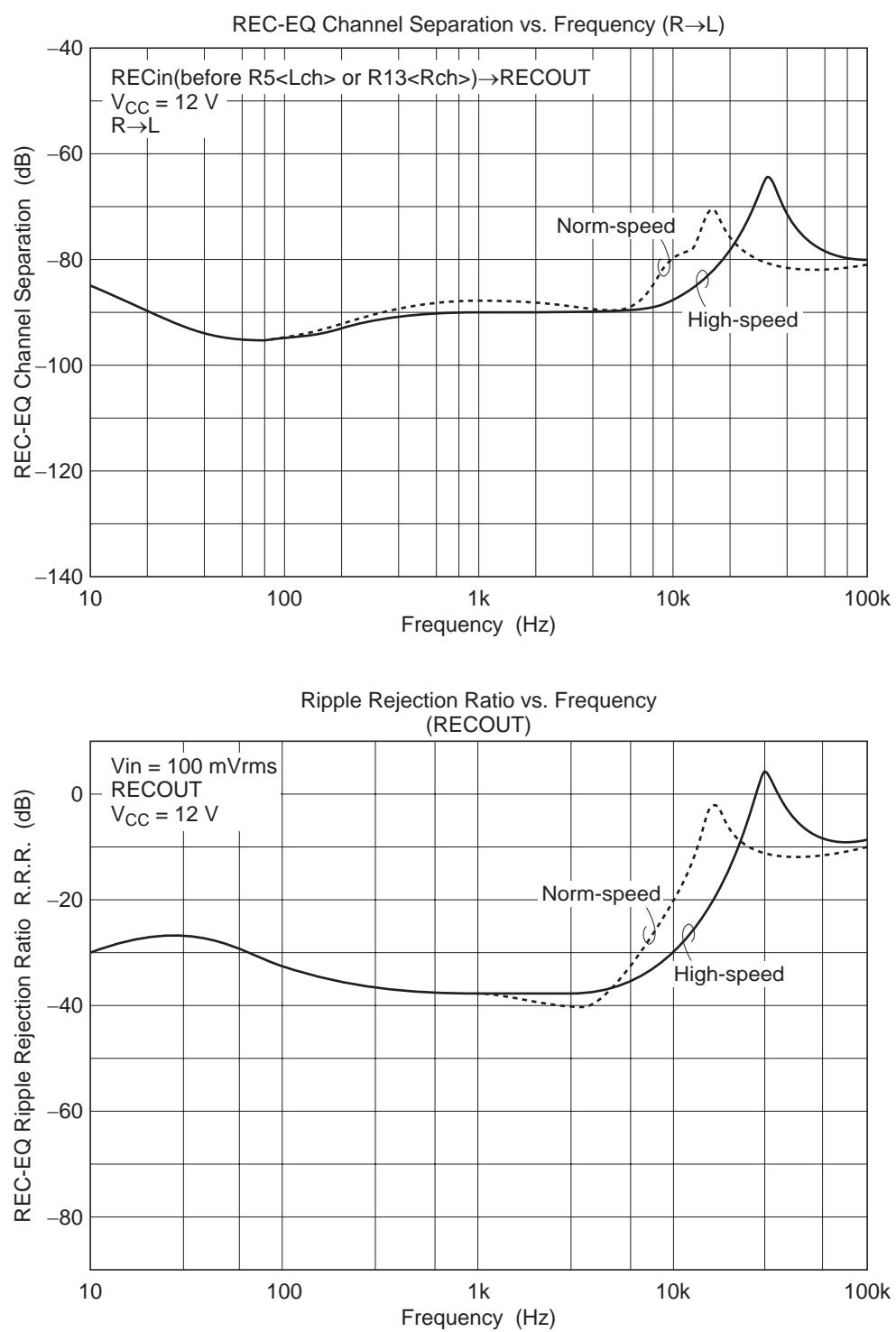


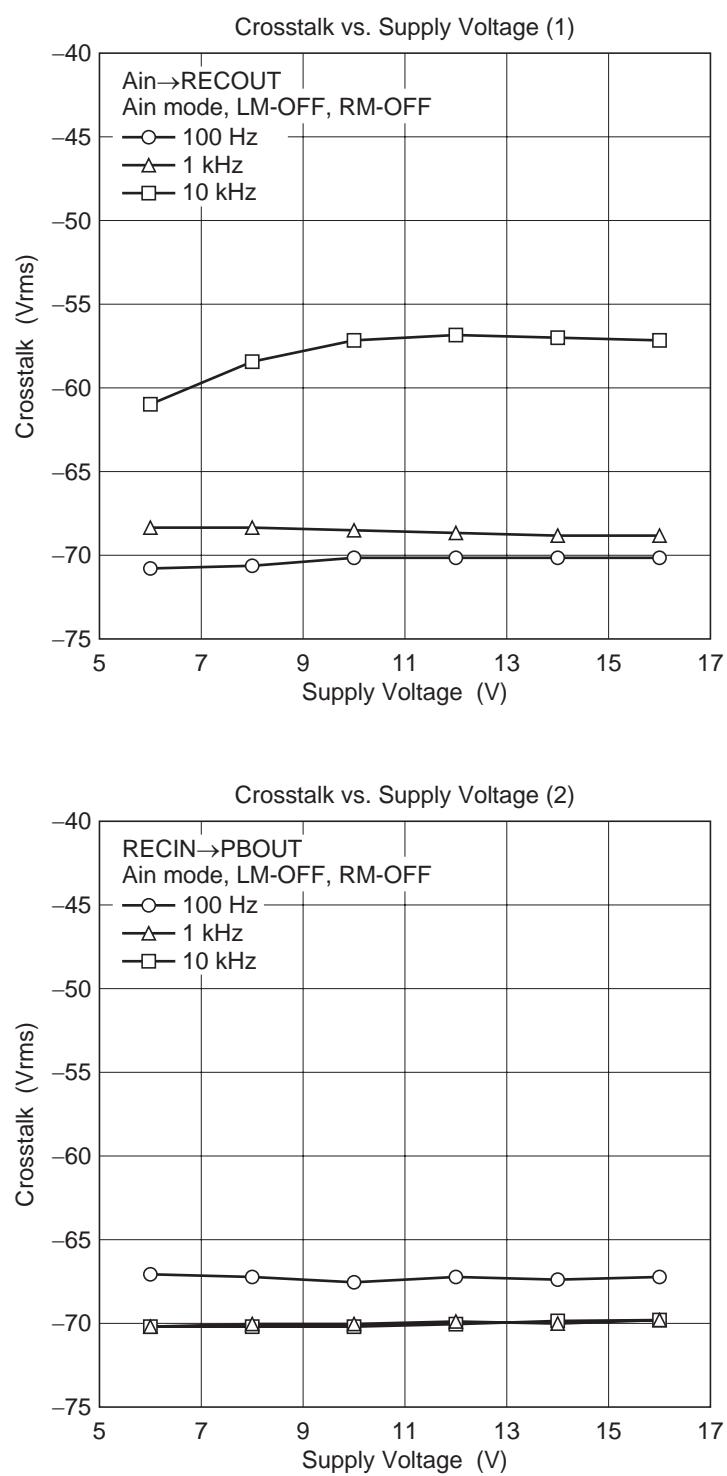


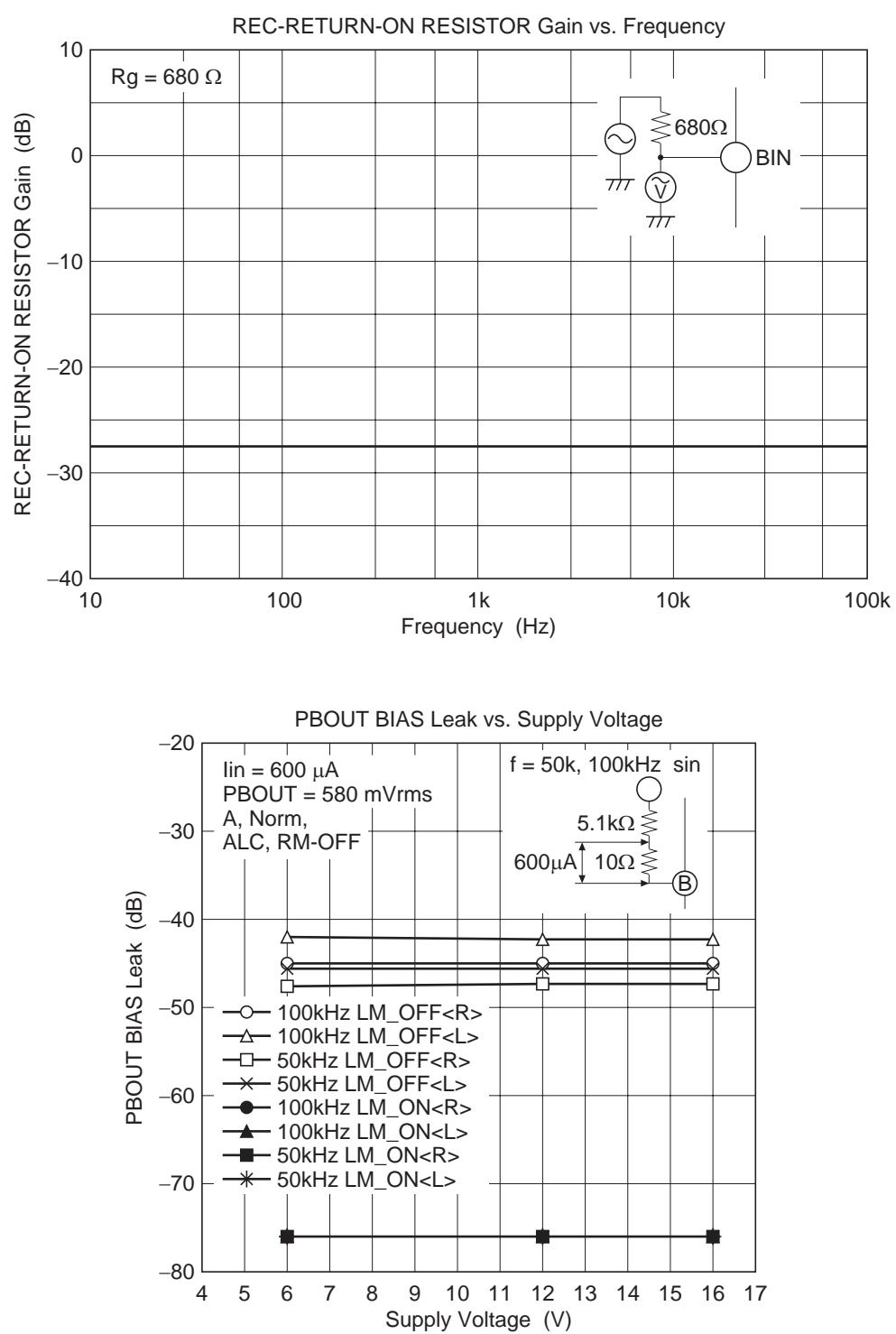






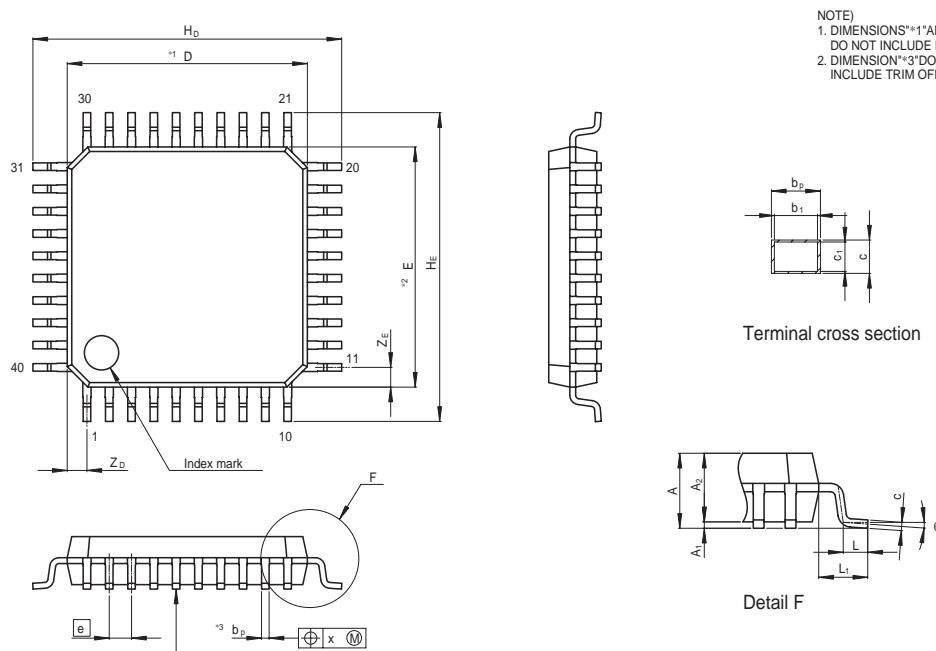






Package Dimensions

JEITA Package Code	RENESAS Code	Previous Code	MASS[Typ.]
P-LQFP40-7x7-0.65	PLQP0040JB-A	FP-40B	0.2g



NOTE)
 1. DIMENSIONS *1 AND *2 DO NOT INCLUDE MOLD FLASH
 2. DIMENSION *3 DOES NOT INCLUDE TRIM OFFSET.

Reference Symbol	Dimension in Millimeters		
	Min	Nom	Max
D	—	7.0	—
E	—	7.0	—
A ₂	—	1.40	—
H _D	8.8	9.0	9.2
H _E	8.8	9.0	9.2
A	—	—	1.70
A ₁	0.08	0.13	0.22
b _p	0.20	0.25	0.30
b ₁	—	0.22	—
c	0.12	0.17	0.22
c ₁	—	0.15	—
θ	0°	—	8°
[e]	—	0.65	—
x	—	—	0.13
y	—	—	0.10
Z _D	—	0.575	—
Z _E	—	0.575	—
L	0.40	0.50	0.60
L ₁	—	1.0	—

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